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January 20177

FUSB252 Type-C CC with High Speed Digital (HSD) Port Protection Switch

Features

- Fully Type-C Port Protection
- Supports USB Type-CTM Specification 1.2
- V_{CC} 0 V- 5.5 V
- 20 V DC Protection on V_{CC}
- 16 V DC protection on HSD Port
- V_{DD} Operating Range, 2.7 V- 5.5 V
- Current Capability: 1 A
- CC R_{ON}: 0.3 Ω Typical
- HSD R_{ON}: 5 Ω Typical
- Wide -3 db Bandwidth: 1 GHz
- Low Power Operation: I_{CC} = 9 µA Typical
- Dead Battery Support (UFP Support when No Power Applied)
- CC Over-Voltage Protection: Typical = 5.6 V

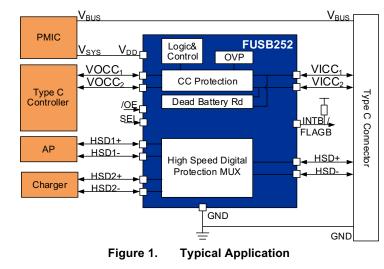
Description

The FUSB252 is an integrated port protection switch for USB Type-C applications. This product will protect HSD+/- and CCx pins when stressed with voltages up to 20 V. Over-Voltage Protection (OVP) at 5.8 V typical will protect the system for Electrical Overstress (EOS) damage. With a fully integrated USB 2.0 switch for HSD+/-, this product can be easily integrated into existing solutions. The HSD switches can pass USB 2.0 signals with bandwidth 1 GHz to maintain signal integrity and eye compliance.

The CC switches have very low R_{ON} of 0.3Ω to minimize signal attenuation. The FUSB252 also provides Dead Battery support per the Type-C specification Additional features include Under-Voltage Lockout (UVLO) and thermal shutdown.

Applications

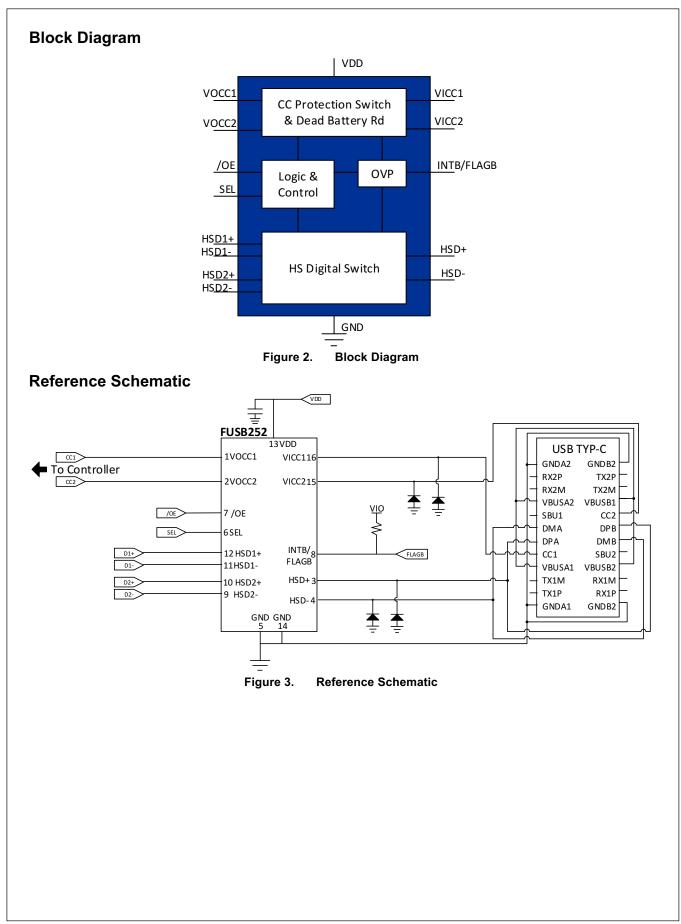
- Smartphones
- Tablets
- Laptops

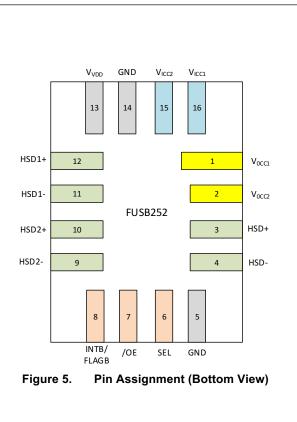


Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method	Top Mark	
FUSB252UMX	-40 to 85°C	16-Lead Ultrathin Molded Leadless Package (UMLP) 1.8 x 2.6 mm	Tape and Reel	UZ	

USB Type- C^{TM} is a trademark of USB Implementers Forum, Inc.





Pin Descriptions

Pin Configuration

V_{0CC1}

V_{0CC2}

HSD+

HSD-

Figure 4.

 V_{ICC1}

16

1

3

4

5

GND

6

SEL

7

/OE

V_{ICC2}

15

FUSB252

GND

14

 V_{VDD}

13

12

11

10

9

8

INTB/

FLAG B

Pin Assignment (Top Through View)

HSD1+

HSD1-

HSD2+

HSD2-

Bump	Name	Туре	Description
Power Interfa	ce		
13	VDD	Power	Power
5,14	GND	Ground	Ground
USB Type-C	Connector Inter	rface Input	
15, 16	VICC1,2	Input	Type C CC Interface OVP protection input, Connect to connector
USB Type-C	Connector Inter	rface Output	
1, 2	VOCC1,2	Output	Type C CC Interface output. Connect to controller
USB High Sp	eed Data Interfa	ace	
3	HSD+	I/O	Common High Speed Digital / USB Data Bus
4	HSD-	I/O	Common High Speed Digital / USB Data Bus
12	HSD1+	I/O	Multiplexed Source Input 1
11	HSD1-	I/O	Multiplexed Source Input 1
10	HSD2+	I/O	Multiplexed Source Input 2
9	HSD2-	I/O	Multiplexed Source Input 2
Signal Interfa	ice		
7	/OE	I/O	Switch Enable
6	SEL	I/O	Switch Select
8	INTB/FLAGB	Output	OVP Interrupt Flag

Table 1. CC Switch Truth Table Configuration

V _{DD}	V _{ICC} Voltage	CC Switch Configuration
	0 V – 5.8 V	OFF Dead Battery Rd Inserted
0 V - UVLO (Not Valid)	5.8 V to 20 V	OFF Dead Battery Rd Inserted
	0 V – 5.8 V	On
2.7 V – 5.5 V (Valid)	5.8 V to 20 V	OFF (OVP)

Table 2. Device Truth Table Configuration

/OE	SEL	VDD	HSD+/HSD-	CC
1	0	Not Valid	X (Open/High-Z)	Dead Battery
0	0	Not Valid	X (Open/High-Z)	Dead Battery
1	Х	Valid	X (Open/High-Z)	On
0	0	Valid	HSD1+/HSD1-	On
0	1	Valid	HSD2+/HSD2-	On

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Min.	Max.	Unit
V_{VDD}	Supply Voltage from V _{DD}			-0.5	12.0	V
V _{VICC}	V _{ICCx} , to GND			-0.5	24	V
V_{SW}	V _{HSD±} , to GND			-5	16	V
$V_{\text{OCC},}V_{\text{SW}}$	V _{OCCx} V _{HSDx+/-} to GND			-0.5	6	V
VCONTROL	DC Input Voltage (S, /OE)			-0.5	V _{VDD}	V
Iccsw	DC CC Switch Current	/ _{HSDx+/-} to GND ut Voltage (S, /OE) Switch Current tput Current ut Diode Current e Temperature Range um Junction Temperature emperature (Soldering, 10 seconds) 000-4-2 System ESD Outor-4-5 Surge ESD				
IUSBSW	DC Output Current	Connector Pins (V _{VDD} , V _{ICCx} , V _{HSD±} ,) Col V _{ICCx} to GND V _{HSD±} to GND Power to GND External Pins to GND (V _{HSD±} , V _{ICCx}) System Side Pin			100	mA
I _{IK}	C Input Diode Current					mA
TSTORAGE	Storage Temperature Range					С
TJ	Maximum Junction Temperature				+150	С
T∟	Lead Temperature (Soldering, 10 seconds)				+260	С
VVDD S VVICC V VSW V VOCC, VSW V VCONTROL I ICCSW I IUSBSW I IIK I TSTORAGE S TJ I TL I	IEC 61000 4 2 System ESD	Connector Pins Air Gap		15		kV
		$\begin{array}{c c c c c c c c } & & & & & & & & & & & & & & & & & & &$	8		ΓV	
	IEC 61000.4-5 Surge ESD	V _{ICCx} to GND		-0.5 -0.5 -0.5 -0.5 -0.5 -0.5 -0.5 -0.5	24	V
	120 01000-4-5 Suige ESD	$V_{\text{HSD}\pm}$ to GND		-16	16	V
		Power to GND		$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		
ESD	Human Body Model, JEDEC JESD22-A114	$\begin{array}{c c c c c c c c c c c c c c c c c c c $				
Vsw Vocc, Vsw Vcontrol Iccsw Iusbsw Iik Tstorage TJ TL		(V _{HSDx±} , V _{OCCx} , S, /OE,		2		kV
	Charged Device Model, JEDEC LESD22-C101	All Pins		1		

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. ON does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{VDD}	Supply Voltage	2.7	4.2	5.5	V
V _{ICC}	Type C Input Voltage	0		5.5	V
Vocc	Type C Output Voltage	0		5.5	V
Iccsw	Maximum CC Switch Current			1	А
V _{CNTRL}	Control Input Voltage (SEL, /OE)	-0.5		V _{VDD}	V
V _{SW}	HSD/USB Switch I/O Voltage	-0.5		4.5	V
TA	Operating Temperature	-40		+85	С

DC Electrical Characteristics

Unless otherwise specified: Recommended T_A and T_J temperature ranges. All typical values are at $T_A=25^\circ\text{C}$ and $V_{DD}=4.2$ V unless otherwise specified.

Symbol	Parameter	V _{DD} (V)	Conditions		T _A = -40 to +85°C T _J =-40 to +125°C		Unit
		55(7)		Min.	Тур.	Max.	
Basic Oper	ation Device						
I	Quiescent Supply Current	2 7 to 5 5	/OE = L, I _{OUT} =0		9		
Icc	Quiescent Supply Current	2.7 to 5.5	/OE = H I _{OUT} =0		9		μA
I _{OFF}	Power-Off Leakage Current	0			3		μA
Basic Oper	ation CC switch						
I _{SD(DB)}	Dead Battery Supply Current	0 to UVLO	Dead Battery State Supply Current		15		uA
R _{ON}	CC Path On Resistance	2.7 to 5.5	I _{OUT} = 200 mA		350	480	mΩ
V _{OV TRIP}	Input OVP Lockout	2.7 to 5.5	V _{ICC} Rising		5.65	6.20	v
VOV_IRP	-		V _{ICC} Falling		5.3		v
V _{OV_HYS}	Input OVP Hysteresis	2.7 to 5.5			0.35		V
Vuvlo	Under-Voltage Lockout	2.7 to 5.5	V _{DD} Rising		2.55	2.70	v
	, , , , , , , , , , , , , , , , , , ,		V _{DD} Falling		2.5		
			Shutdown Threshold		150		°C
TSD	Thermal Shutdown ⁽¹⁾		Return from Shutdown		130		
			Hysteresis		20		
Rd	Dead Battery Pull-Down	0 to UVLO	Dead Battery Resistance	4.08	5.10	6.12	kΩ
i tu	Rd Resistance		Voltage on Pin	0.25		2.6	V
Basic Oper	ation HSD Switch						
V _{OV_TRIP}	Input OVP Lockout	2.7 to 5.5	V _{HSD±} Rising		4.4	5.0	v
00111			V _{HSD±} Falling		4.1		-
V_{OV_HYS}	Input OVP Hysteresis	2.7 to 5.5			0.3		V
V _{UV_TRIP}	Input Under-Voltage Lockout	2.7 to 5.5			-1.2		V
V _{IH}	Input Voltage High	2.7 to 5.5		1.3			V
VIL	Input Voltage Low	2.7 to 5.5				0.5	V
l _{iN}	Control Input Leakage	2.7 to 5.5	$V_{SW} = 0$ to V_{DD}		0.1		μA
le-	Off State Leakage	4.2	0≤HSDn ≤3.6 V		2		μA
l _{oz}	On State Leakaye	4.2	0≤HSD1n _± , HSD2n _± ≤3.6 V		100		nA
R _{ON}	HS Switch On Resistance	4.2	V _{SW} = 0.4 V, I _{ON} = -8 mA		5		Ω
ΔR_{ON}	HS Delta R _{ON}	4.2	V _{SW} = 0.4 V, I _{ON} = -8 mA		0.1		Ω

Note:

1. Guaranteed by characterization, not production tested

AC Electrical Characteristics

Unless otherwise specified: Recommended T_A and T_J temperature ranges. All typical values are at T_A =25°C and V_{DD} =3.8 V unless otherwise specified.

Symbol	Parameter	V _{DD} (V)	Conditions			40 to +85°C 0 to +125°C	
		- 55 (-)		Min.	Тур.	Max.	
CC Switch	Timing Parameter				•	•	
t _{OVP}	Response Time ⁽²⁾	2.7 to 5.5	I_{OUT} = 0.2 A, C _L = 200 pF, V _{ICCx} 5 V to 6 V		0.5	1.0	μs
t _{ON}	Turn-On Time		VDD Rising 2 V to 3 V		25		ms
T _{MBB}	Make-Before-Break	2.7 to 5.5	VDD Rising 2 V to 3 V		600		ns
CC Switch	Capacitance						
Con	Switch Path On Capacitance ⁽²⁾	2.7 to 5.5			100		pF
CC Switch	Bandwidth						
BW	PD Traffic Bandwidth ⁽²⁾	2.7 to 5.5	R_L = 50 Ω , C_L = 200 pF		25		MHz
HSD Swite	h Timing Parameter						
t _{OVP}	Response Time ⁽²⁾	2.7 to 5.5	I_{OUT} = 0.2 A, V _{D±} 4 V to 5 V		0.5	1.0	μs
t _{ON}	Turn-On Time, /OE to Output ⁽²⁾	2.7 to 5.5			25		ms
toff	Turn-Off Time, /OE to Output ⁽²⁾	2.7 to 5.5	$\label{eq:relation} \begin{array}{l} R_{L} = 50 \ \Omega, \ C_{L} = 5 \ pF, \\ V_{SW} = 0.8 \ V \end{array}$		100	400	ns
t _{PD}	Propagation Delay ⁽²⁾	2.7 to 5.5	R_L = 50 Ω , C_L = 5 pF,		0.25		ns
Т _{ввм}	Break-Before-Make ⁽²⁾	2.7 to 5.5	R_L = 50 Ω , C_L = 5 pF, V _{SWx} = 0.8 V SEL= H <-> L		100		μs
O _{IRR}	Off Isolation	2.7 to 5.5	R_L = 50 Ω , f = 240 MHZ		-25		dB
Xtalk	Non-Adjacent Channel Crosstalk	2.7 to 5.5	R_L = 50 Ω , f = 240 MHZ		-40		dB
HSD Swite	ch Capacitance						
C _{IN}	Control Pin Input Capacitance ⁽²⁾	0			1.5		
C _{ON}	HSD+/HSD- On Capacitance ⁽²⁾	2.7 to 5.5	/OE = L, f = 240 MHz,		4		pF
C_{OFF}	HSD1 _x , HSD2 _x Off Capacitance ⁽²⁾	2.7 to 5.5	/OE = H		2.5		
USB Swite	h Bandwidth				1	1	•
BW	-3 db Bandwidth ⁽²⁾	2.7 to 5.5	$R_L = 50 \Omega, C_L = 0 pF$		1400		MHz
0 * *		2.7 to 5.5	R_L = 50 Ω, C_L = 5 pF		560		
USB High-	Speed-Related						
$t_{\text{SK}(\text{P})}$	Skew of Opposite Transitions of the Same Output ⁽²⁾		$R_L = 50 \Omega, C_L = 5pF$		25		ps
tJ	Total Jitter ⁽²⁾		R_L = 50 Ω, C_L = 5 pF, t_R = t_F = 500 ps (10-90%) at 480 Mbps (PRBS=2 ¹⁵ – 1)		200		ps

Note:

2. Guaranteed by characterization, not production tested.

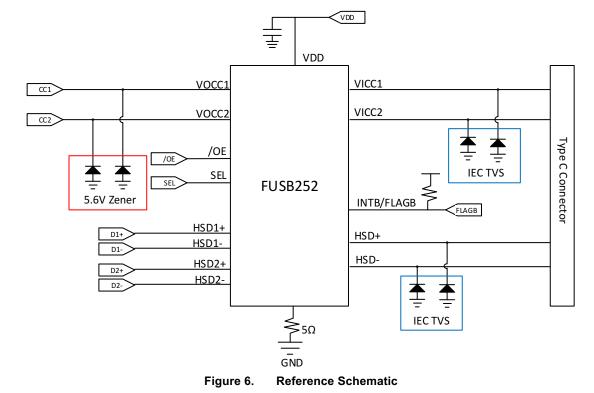
Operation and Application Description

Out of Spec Surge/Spike Voltage due to Hot Plug

The FUSB252 protects end systems against 20 V DC on the CC pin, in cases where the FUSB252 is tested to mimic a hot plug event, a fully charged cable connected to a power supply set to 20 V is used to zap the VICC pins of the device. In these cases, the inductance of the cable causes voltage spikes that are higher than the absolute maximum ratings of the of the VICC pins. These voltages can cause damage to the VOCC pins. This scenario does not occur in normal usage. The Type-C specification prevents the plug from having 20V on VBUS from a PD source prior to a PD contract being completed. When the 20 V potential is on VBUS and shorted to the CC pin, it causes a detach and the voltage spikes are less likely to occur. The following reference circuit is required when the application calls for additional protection to protect against such event as hot plug.

Application Specific Schematic

- Place a 5 V to 6 V rated Zener TVS diode such as (CZRF52C5V6 or CD1005-Z5V1) on the VOCC pin, and a 5 Ω resistor to device ground to prevent the FUSB252 from being damaged during these tests. With this additional protection if is also important to select the right external VICC IEC TVS for the best overall performance.
- Without the additional protection the device by itself can withstand up to 9 V under the same hot plug condition

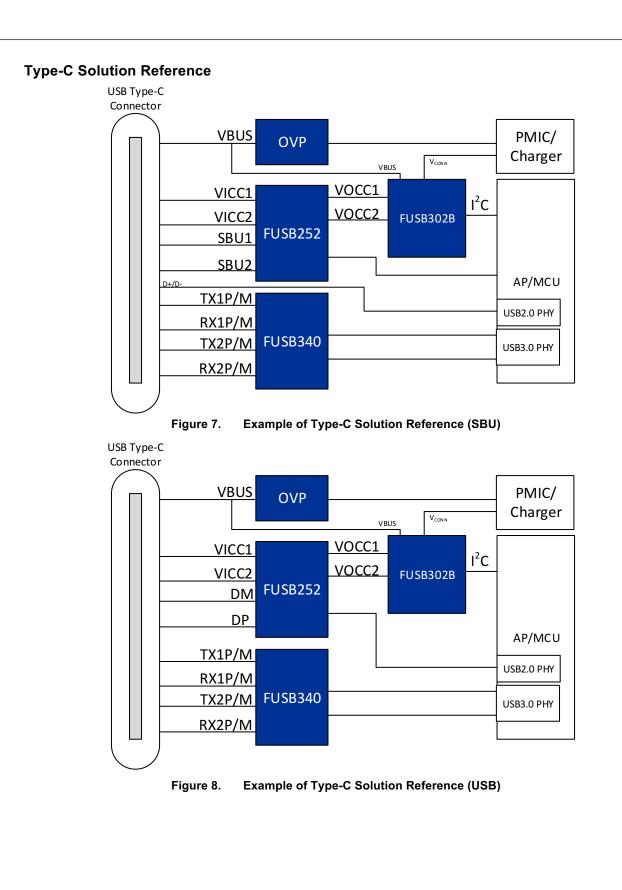


Over-Voltage Protection

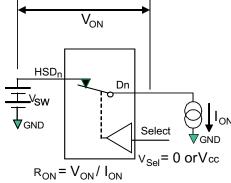
When over-voltage event is detected, device will activate OVP to shutdown the switch within t_{OVP} , as well as signal the FLAGB to indicate there is OV event to the system.

Fault Reporting

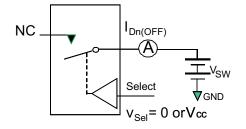
Upon the detection of an over-voltage event, the INTB/FLAGB signals the fault by activating LOW.



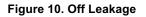
Test Diagrams

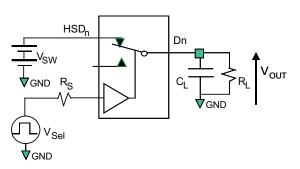




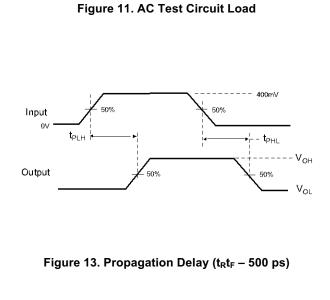


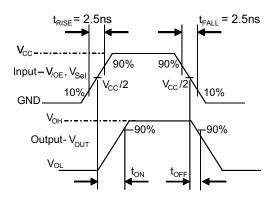
**Each switch port is tested separately

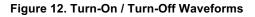




 $R_L^{},\,R_S^{},\,and\,C_L^{}$ are functions of the application environment (see AC Tables for specific values) C₁ includes test fixture and stray capacitance.







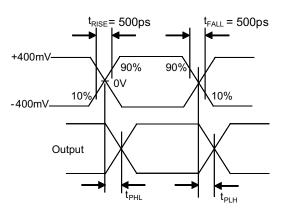
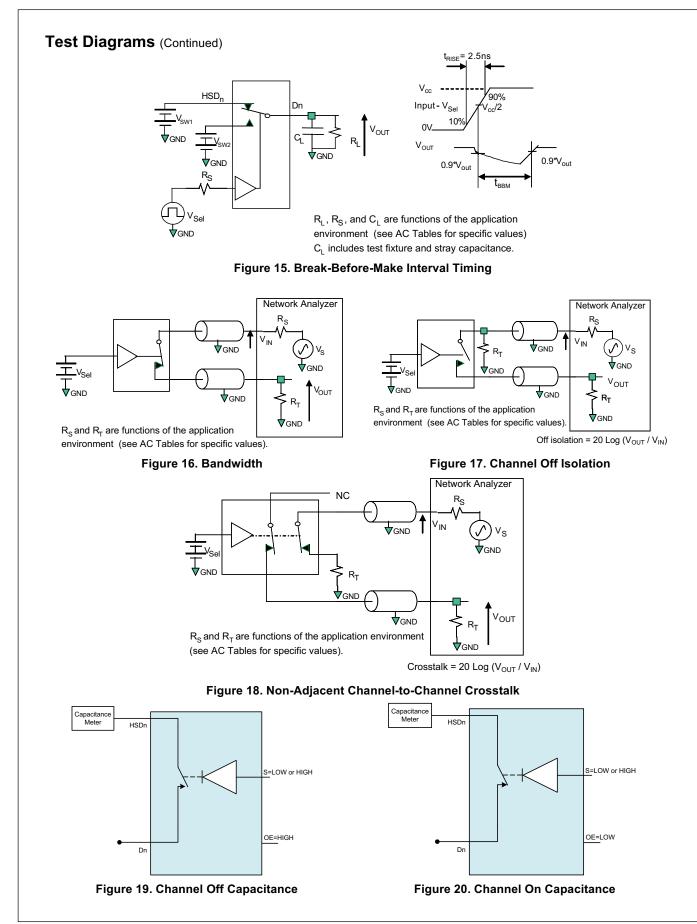
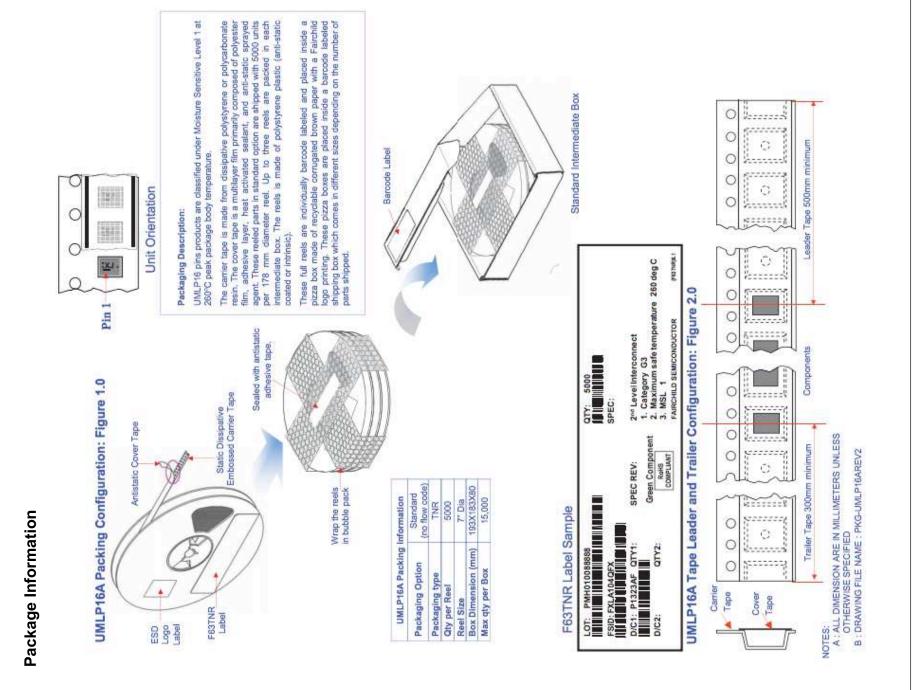


Figure 14. Intra-Pair Skew Test t_{SK(P)}

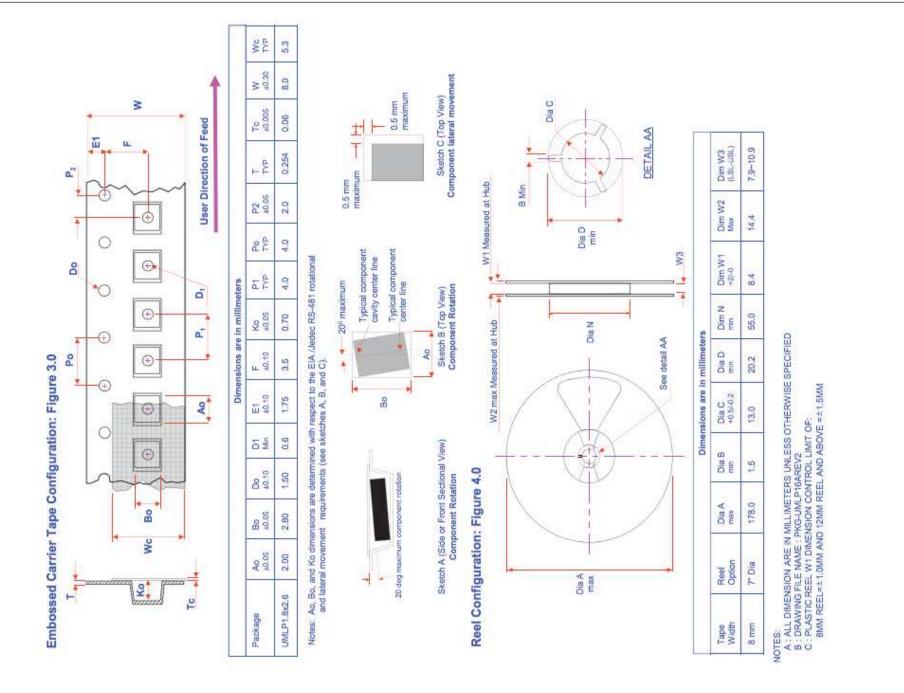




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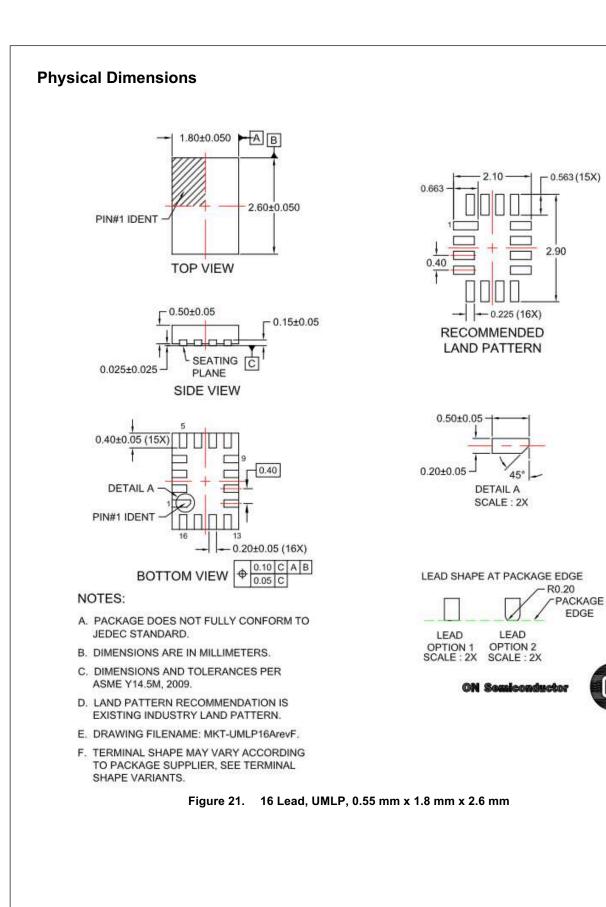


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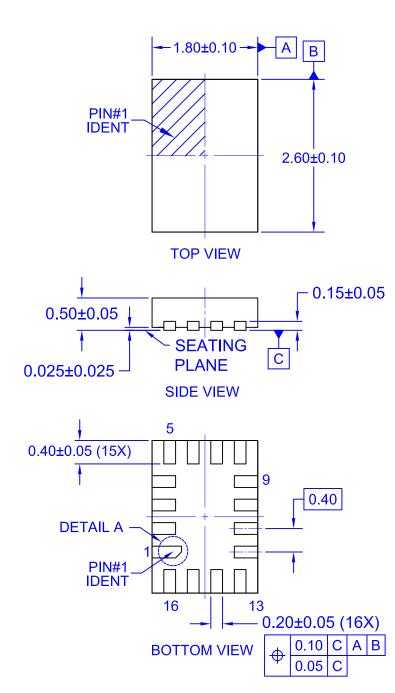
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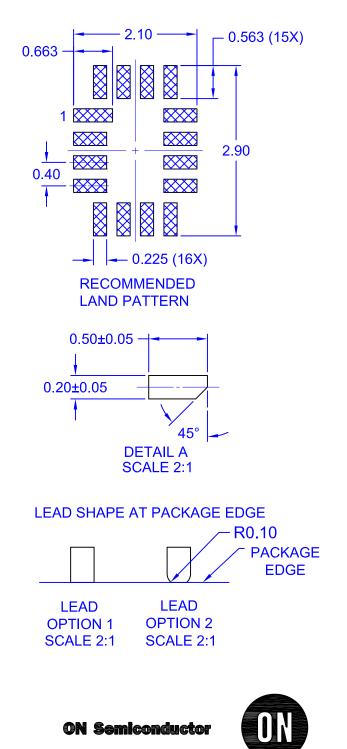
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